

View Online at <https://aerobasegroup.com/nsn/5961-00-475-8523>

Inclosure Material:

Metal all transistor

Overall Length:

0.190 inches all transistor

Terminal Length:

0.500 inches all transistor

Overall Diameter:

0.220 inches all transistor

Internal Configuration:

Junction contact all transistor

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-18 all transistor

Electrode Internally-electrically Connected To Case:

Collector all transistor

Internal Junction Configuration:

Npn all transistor

Component Function Relationship:

Matched

Component Name And Quantity:

2 transistor

Mounting Method:

Terminal all transistor

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

60.0 collector to base voltage/static/emitter open all transistor and 45.0 collector to emitter voltage/static/base open all transistor and 6.0 emitter to base voltage, static, collector open all transistor

Current Rating Per Characteristic:

30.00 milliamperes source cutoff current all transistor

Power Rating Per Characteristic:

600.0 milliwatts small-signal input power, common-collector preset all transistor

Test Data Document:

18876-10183001 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

3 uninsulated wire lead all transistor

Shelf Life:

N/a

Unit Of Measure:

--

Demilitarization:

No

Fiig:

A110a0